

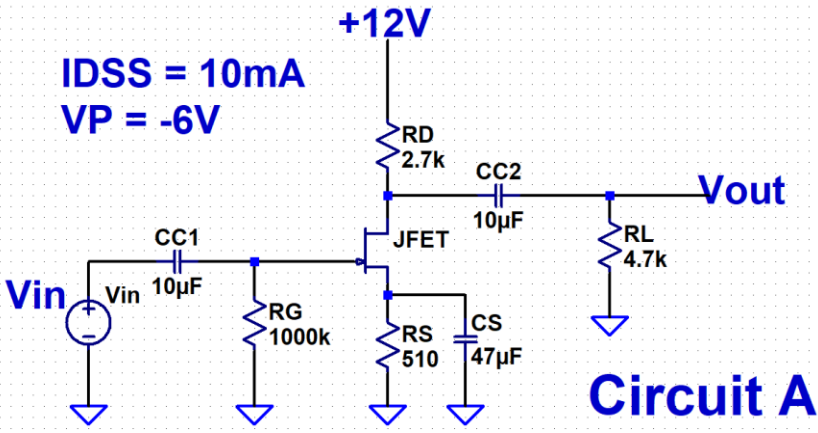
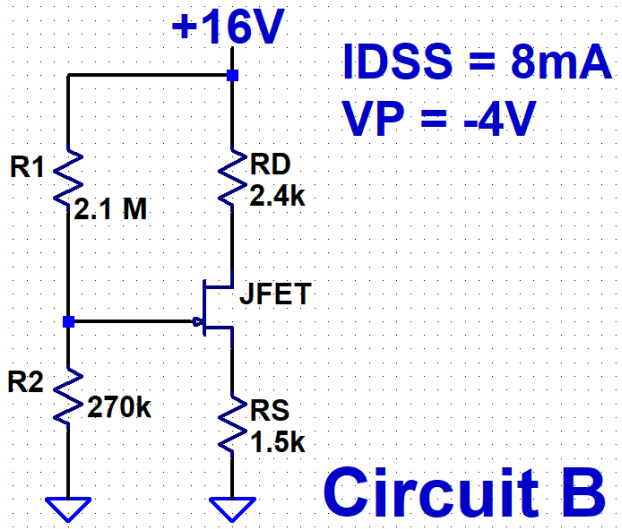
**K. J. Somaiya College of Engineering, Mumbai-77**  
 (Autonomous College Affiliated to University of Mumbai)  
 Semester: July – November 2019

**Max. Marks: 30**  
**Class: SY B. Tech**  
**Branch: ETRX**

**Duration: 1hr.15 min.**  
**Semester: III**  
**Test 2**  
**Course Code:2UEXC302**

**Full name of the course : Basic Electronic Circuits**

Q. No	Questions	Marks
Q.1	<p>Consider the circuit shown in figure 1. Transistor parameters are <math>\beta = 100</math>, <math>V_A = 100</math> V. Determine</p> <ol style="list-style-type: none"> <li>1. <math>R_i</math></li> <li>2. <math>A_v = V_o/V_s</math> with load resistor</li> <li>3. <math>A_v = V_o/V_s</math> without load resistor</li> <li>4. <math>R_o</math></li> </ol> <div style="text-align: center;"> <p style="text-align: center;">Figure 1</p> </div>	15
<b>OR</b>		
	<p>Consider the circuit shown in figure 2. Transistor parameters are <math>\beta = 100</math>, <math>V_{BE(ON)} = 0.7</math> V, <math>V_A = \infty</math>. Design bias stable circuit such that <math>I_{CQ} = 0.5</math> mA, <math>V_{CEQ} = 2.5</math> V and <math>A_v = - 8</math>.</p> <div style="text-align: center;"> <p style="text-align: center;">Figure 2</p> </div>	

<p>Q2.</p>	<p>a) Find hybrid pi parameter <math>g_m</math> for circuit A shown below:</p>  <p><b>Circuit A</b></p> <p>b) JFET is a voltage controlled device. Justify</p>	<p>4</p> <p>3</p>
<p>Q3.</p>	<p>Find <math>I_D</math>, <math>V_{GS}</math> and <math>V_{DS}</math> for circuit B either by analytical or graphical method.</p>  <p><b>Circuit B</b></p>	<p>8</p>